

# Low Noise, High Speed Precision Operational Amplifiers

### **FEATURES**

- Guaranteed 4.5nV/√Hz 10Hz Noise
- Guaranteed 3.8nV/√Hz 1kHz Noise
- 0.1Hz to 10Hz Noise, 60nVp-p, Typical
- Guaranteed 5 Million Min. Voltage Gain,  $R_L = 2k\Omega$
- Guaranteed 2 Million Min. Voltage Gain,  $R_1 = 600\Omega$
- Guaranteed 60µV Max. Offset Voltage
- Guaranteed 1.0µV/°C Max. Drift with Temperature
- Guaranteed 11V/µsec Min. Slew Rate (LT1037)
- Guaranteed 110dB Min. CMRR

### **APPLICATIONS**

- Low Noise Signal Processing
- Microvolt Accuracy Threshold Detection
- Strain Gauge Amplifiers
- Direct Coupled Audio Gain Stages
- Sine Wave Generators
- Tape Head Preamplifiers
- Microwave Preamplifiers

### DESCRIPTION

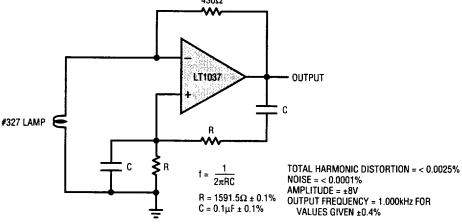
Next to the LT1028, the LT1007/LT1037 series features the lowest noise performance available to date for monolithic operational amplifiers:  $2.5 \text{nV}/\sqrt{\text{Hz}}$  wideband noise (less than the noise of a  $400\Omega$  resistor), 1/f corner frequency of 2Hz and 60nV peak-to-peak 0.1Hz to 10Hz noise. Low noise is combined with outstanding precision and speed specifications:  $20\mu\text{V}$  offset voltage,  $0.3\mu\text{V}/^{\circ}\text{C}$  drift, 126dB common mode and power supply rejection, and 60MHz gain-bandwidth-product on the decompensated LT1037, which is stable for closed loop gains of 5 or greater.

The voltage gain of the LT1007/LT1037 is an extremely high 20 million driving a  $2k\Omega$  load and 12 million driving a  $600\Omega$  load to  $\pm 10V$ .

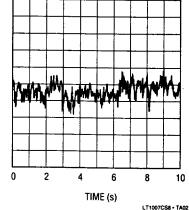
In the design, processing, and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications have been spectacularly improved compared to competing amplifiers.

The sine wave generator application shown below utilizes the low noise and low distortion characteristics of the LT1037.

### Ultra-Pure 1kHz Sine Wave Generator



/OLTAGE NOISE (20nV/DIV)



0.1Hz to 10Hz Noise

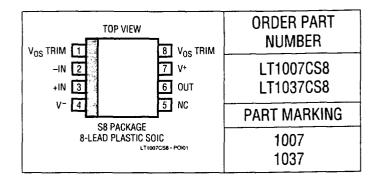
LT1007CS8 - TA0

### 2

### **RBSOLUTE MAXIMUM RATINGS**

# Supply Voltage .......Equal to Supply Voltage Output Short Circuit Duration ......Indefinite Differential Input Current (Note 5) ......±25mA Operating Temperature Range ......0°C to 70°C Storage Temperature Range All Devices ......-65°C to 150°C Lead Temperature (Soldering, 10 sec.) .....300°C

### PACKAGE/ORDER INFORMATION



## **ELECTRICAL CHARACTERISTICS** $V_s = \pm 15V$ , $T_A = 25^{\circ}C$ , unless otherwise noted.

SYMBOL	PARAMETER		CONDITIONS	MIN	LT1007C LT1037C TYP	MAX	UNITS
V <sub>OS</sub>	Input Offset Voltage		(Note 1)	INTER	20	60	μV
ΔV <sub>OS</sub> ΔTime	Long Term Input Offset Voltage Stability		(Notes 2 and 3)		0.2	1.0	μV/Mo
los	Input Offset Current				12	50	nA
I <sub>B</sub>	Input Bias Current				±15	±55	nA
e <sub>n</sub>	Input Noise Voltage		0.1Hz to 10Hz (Note 3)		0.06	0.13	μVр-р
	Input Noise Voltage Density		f <sub>O</sub> = 10Hz (Note 3) f <sub>O</sub> = 1000Hz (Note 3)		2.8 2.5	4.5 3.8	nV/√Hz nV/√Hz
i <sub>n</sub>	Input Noise Current Density		f <sub>O</sub> = 10Hz (Note 3) f <sub>O</sub> = 1000Hz (Note 3)		1.5 0.4	4.0 0.6	pA/√Hz pA/√Hz
	Input Resistance—Common Mode				5		GΩ
	Input Voltage Range			±11.0	±12.5		V
CMRR	Common Mode Rejection Ratio		V <sub>CM</sub> = ±11V	110	126		dB
PSRR	Power Supply Rejection Ratio		V <sub>S</sub> = ±4V to ±18V	106	126		dB
A <sub>VOL</sub>	Large Signal Voltage Gain		$\begin{aligned} R_L &\geq 2k\Omega, \ V_0 = \pm 12V \\ R_L &\geq 1k\Omega, \ V_0 = \pm 10V \\ R_L &\geq 600\Omega, \ V_0 = \pm 10V \end{aligned}$	5.0 3.5 2.0	20.0 16.0 12.0		V/μV V/μV V/μV
V <sub>OUT</sub>	Maximum Output Voltage Swing		$\begin{aligned} R_L &\geq 2k\Omega \\ R_L &\geq 600\Omega \end{aligned}$	±12.5 ±10.5	±13.5 ±12.5		V
SR	Slew Rate	LT1007 LT1037	$R_{L} \ge 2k\Omega$ $A_{VCL} \ge 5$	1.7 11	2.5 15		V/μs V/μs
GBW	Gain-Bandwidth Produc	t LT1007 LT1037	$f_0 = 100kHz \text{ (Note 4)}$ $f_0 = 10kHz  (Note 4), (AVCL \ge 5)$	5.0 45	8.0 60		MHz MHz
Z <sub>0</sub>	Open Loop Output Resistance		$V_0 = 0, I_0 = 0$		70		Ω
P <sub>d</sub>	Power Dissipation	LT1007 LT1037	·		80 85	140 140	mW mW

# **ELECTRICAL CHARACTERISTICS** $V_S = \pm 15V, \ 0^{\circ}C \le T_A \le 70^{\circ}C, \ unless \ otherwise \ noted.$

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1007C LT1037C TYP	MAX	UNITS
Vos	Input Offset Voltage	(Note 1)	•		35	110	μ۷
$\frac{\Delta V_{OS}}{\Delta Temp}$	Average Input Offset Drift	(Note 6)	•		0.3	1.0	μV/°C
I <sub>OS</sub>	Input Offset Current		•		15	70	nA
l <sub>B</sub>	Input Bias Current		•		±20	±75	nA
	Input Voltage Range		•	±10.5	±11.8		V
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> = ±10.5V	•	106	120		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5 \text{V to } \pm 18 \text{V}$	•	102	120		dB
A <sub>VOL</sub>	Large Signal Voltage Gain	$R_L \ge 2k\Omega$ , $V_0 = \pm 10V$ $R_L \ge 1k\Omega$ , $V_0 = \pm 10V$	•	2.5 2.0	18.0 14.0		V/μV V/μV
V <sub>OUT</sub>	Maximum Output Voltage Swing	$R_L \ge 2k\Omega$	•	±12.0	±13.6		ν
$P_d$	Power Dissipation		•		90	160	mW

The • denotes the specifications which apply over full operating temperature range.

**Note 1:** Input Offset Voltage measurements are performed by automatic test equipment approximately 0.5 seconds after application of power.

**Note 2:** Long Term Input Offset Voltage Stability refers to the average trend line of Offset Voltage vs Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in  $V_{OS}$  during the first 30 days are typically  $2.5\mu V$ .

Note 3: This parameter is tested on a sample basis only.

Note 4: This parameter is guaranteed by design and is not tested.

**Note 5:** The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds ±0.7V, the input current should be limited to 25mA.

Note 6: The Average Input Offset Drift performance is within the specifications unnulled or when nulled with a pot having a range of  $8k\Omega$  to  $20k\Omega$ .